



ZDT6790

COMPLEMENTARY MEDIUM POWER HIGH GAIN TRANSISTOR IN SM-8 PACKAGE

Features

- NPN Transistor
 - BV_{CEO} > 45
 - V_{CE(sat)} < 100mV @ I_C= 100mA
 - Continuous Current I_C = 2A
- PNP Transistor
 - BV_{CEO} > -40V
 - V_{CE(sat)} < -250mV @ I_C= -500mA
 - Continuous Current I_C = -2A
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

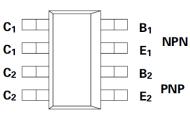
Mechanical Data

- Case: SM-8 (8 LEAD SOT223)
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.117 grams (Approximate)

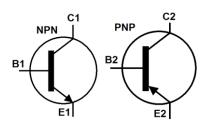
SM-8



Top View



Top View Pin Out



Equivalent Circuit

Ordering Information (Note 4)

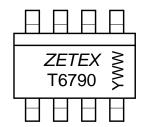
Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZDT6790TA	T6790	7	12	1,000
ZDT6790TC	T6790	13	12	4,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

SM-8



T6790 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W$ = Week Code (01~53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	NPN	PNP	Unit
Collector-Base Voltage	V _{CBO}	45	-50	V
Collector-Emitter Voltage	V _{CEO}	45	-40	V
Emitter-Base Voltage	V _{EBO}	7	-7	V
Continuous Collector Current	Ic	2	-2	Α
Peak Pulse Current (Note 5)	I _{CM}	6	-6	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Collector Power Dissipation	(Note 5)	В	2.25	W	
Collector Fower Dissipation	(Note 6)	P _D	2.75	VV	
Thermal Decistores, Junction to Ambient	(Note 5)	Ь	55.60	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	45.50	C/VV	
Thermal Resistance, Junction to Leads (Note 7)		$R_{\theta JL}$	30.68	°C/W	
Operating and Storage Temperature Range		$T_{J,}T_{STG}$	-55 to +150	°C	

ESD Ratings (Note 8)

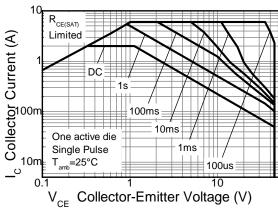
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

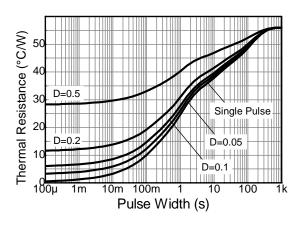
- For a device with any single die active and mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
 Same as Note 5, except both die are active and equally sharing power.
 Thermal resistance from junction to solder-point (at the end of the collector lead).
 Refer to JEDEC specification JESD22-A114 and JESD22-A115.



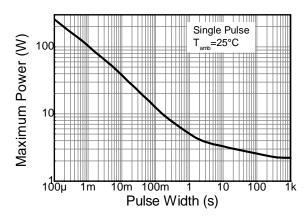
Thermal Characteristics and Derating Information



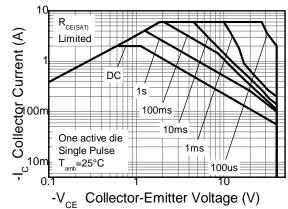
NPN Safe Operating Area



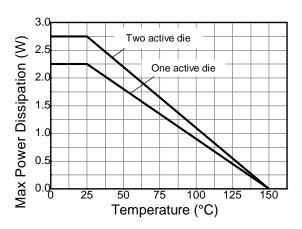
Transient Thermal Impedance



Pulse Power Dissipation



PNP Safe Operating Area



Derating Curve



NPN - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

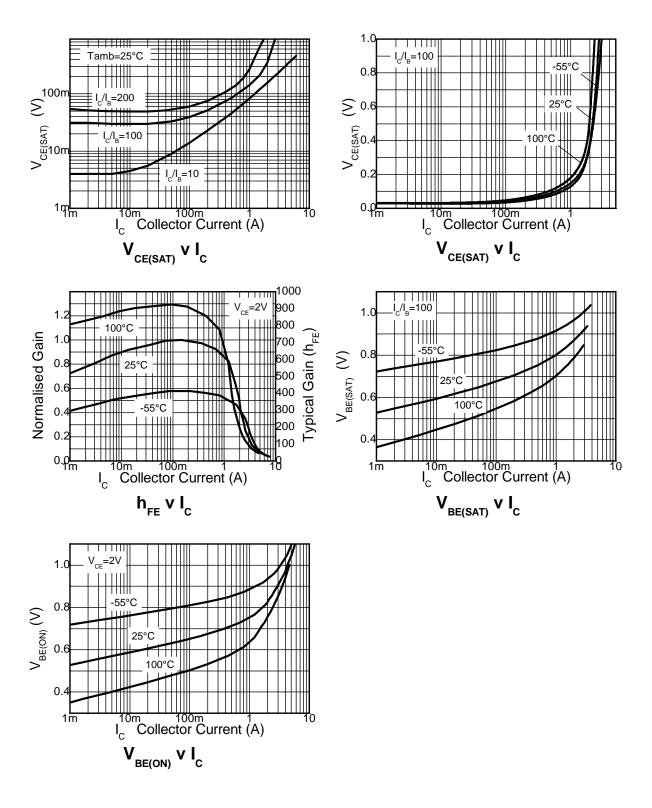
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	45	_	_	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	45	_	_	V	$I_C = 10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	_	V	$I_E = 100 \mu A$
Collector Cut-Off Current	I _{CBO}	_	_	100	nA	V _{CB} = 35V
Emitter Cut-Off Current	I _{EBO}	_	-	100	nA	$V_{EB} = 6V$
		500	-	_		$I_C = 100 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Transfer Static Ratio (Note 9)	h _{FE}	400	_	_		$I_C = 1A$, $V_{CE} = 2V$
		150	_	_		$I_C = 2A$, $V_{CE} = 2V$
Callegator Fraitter Cataration Voltage (Nets O)	.,	_	_	100	mV	I _C = 100mA, I _B = 0.5mA
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	_	_	500		$I_C = 1A$, $I_B = 5mA$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	_	_	900	mV	$I_C = 1A, I_B = 10mA$
Base-Emitter Turn-on Voltage (Note 9)	V _{BE(on)}	_	_	900	mV	I _C = 1A, V _{CE} = 2V
Transitional Frequency (Note 9)	f _T	150	_	_	MHz	$I_C = 50$ mA, $V_{CE} = 5$ V, $f = 50$ MHz
Input Capacitance	C _{ibo}	_	200	_	pF	$V_{EB} = 0.5V$, $f = 1MHz$
Output Capacitance	C _{obo}	_	16	_	pF	V _{CB} = 10V, f = 1MHz
Switching Time	ton		33		ns	$V_{CC} = 10V, I_{C} = 500mA,$
Switching fillie	t _{off}		1,300		ns	$I_{B1} = 50 \text{mA}, I_{B2} = 50 \text{mA}$

Note:

9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s.$ Duty cycle $\leq 2\%.$



NPN - Typical Electrical Characteristics





PNP - Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_CBO	-50		_	V	$I_{C} = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV_CEO	-40	1	_	V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV_{EBO}	-7		_	V	$I_E = -100 \mu A$
Collector Cut-Off Current	I _{CBO}	_	_	-100	nA	V _{CB} = -30V
Emitter Cut-Off Current	I _{EBO}	_	_	-100	nA	$V_{EB} = -6V$
DC Current Transfer Static Ratio (Notes 9)	h _{FE}	300 250 200 150	1111	800 — — —		$I_{C} = -10$ mA, $V_{CE} = -2$ V $I_{C} = -500$ mA, $V_{CE} = -2$ V $I_{C} = -1$ A, $V_{CE} = -2$ V $I_{C} = -2$ A, $V_{CE} = -2$ V
Collector-Emitter Saturation Voltage (Notes 9)	V _{CE(sat)}	_	111	-250 -450 -750	mV	$I_C = -500$ mA, $I_B = -5$ mA $I_C = -1$ A, $I_B = -10$ mA $I_C = -2$ A, $I_B = -50$ mA
Base-Emitter Saturation Voltage (Notes 9)	$V_{BE(sat)}$	_	_	-1,000	mV	$I_C = -1A$, $I_B = -10mA$
Base-Emitter Turn-on Voltage (Notes 9)	$V_{BE(on)}$	_	-750	_	mV	$I_C = -1A$, $V_{CE} = -2V$
Transitional Frequency (Notes 9)	f⊤	100		_	MHz	$I_C = -50 \text{mA}, V_{CE} = -5 \text{V},$ f = 50 MHz
Input Capacitance	C _{ibo}	_	225	_	pF	$V_{EB} = -0.5V, f = 1MHz,$
Output Capacitance	C _{obo}	_	24	_	pF	V _{CB} = -10V, f = 1MHz,
Switching Time	t _{on}	_	35	_	ns	V _{CC} = -10V, I _C = -500mA,
Switching Time	t _{off}		600		ns	$I_{B1} = -50 \text{mA}, I_{B2} = -50 \text{mA}$

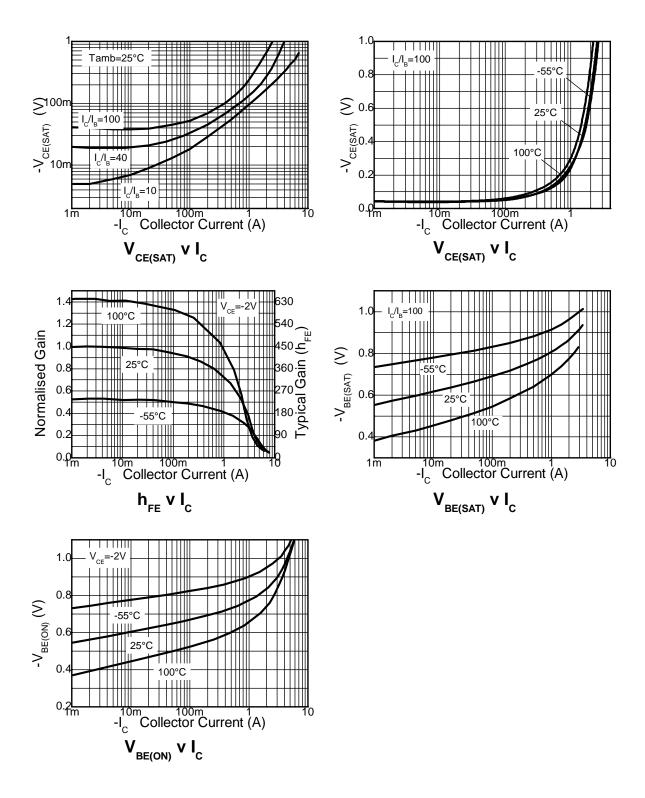
Note:

9. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

October 2015



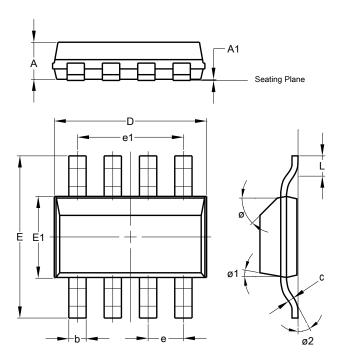
PNP - Typical Electrical Characteristics





Package Outline Dimensions

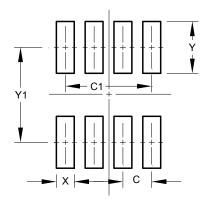
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SM-8						
Dim	Min Max Typ					
Α		1.70	1.60			
A1	0.02	0.10	0.04			
b	0.70	0.90	0.80			
С	0.24	0.32	0.28			
D	6.30	6.30 6.70 6.60				
е	1.53 REF					
e1	4.59 REF					
Е	6.70	6.70 7.30 7.00				
E1	3.30 3.70 3.50					
L	0.75 1.00 0.90					
Ø	45°					
Ø1	- 15° -					
Ø2	-	-	10°			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	1.52
C1	4.6
Х	0.95
Y	2.80
Y1	6.80



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